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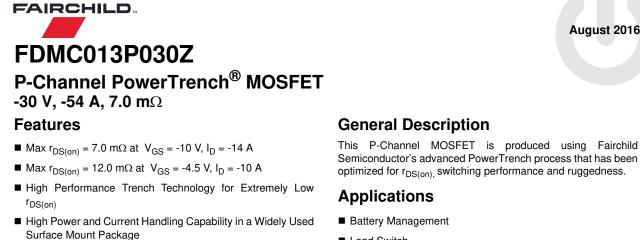


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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- Load Switch
- Тор Bottom Pin 1 S S S G 4



Termination is Lead-free and RoHS Compliant ■ HBM ESD Capability Level > 4 kV Typical (Note 4)

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted.

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			-30	V	
V _{GS}	Gate to Source Voltage			±25	V	
ID	Drain Current -Continuous	T _C = 25 °C	(Note 5)	-54		
	Drain Current -Continuous	T _C = 100 °C	(Note 5)	-35		
	-Continuous	T _A = 25 °C	(Note 1a)	-14	Α	
	-Pulsed		(Note 4)	-309		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	54	mJ	
P _D	Power Dissipation	T _C = 25 °C		30		
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.4		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	4.2	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note 1a	53	C/ W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC013P030Z	FDMC013P030Z	MLP 3.3x3.3	13 "	12 mm	3000 units

D

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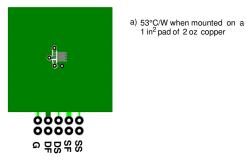
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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units	
Off Chara	octeristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \ \mu A, \ V_{GS} = 0 \ V$	-30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		-13		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 V, V_{GS} = 0 V$			-1	μA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = -250 μA	-1	-1.6	-3	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		5		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = -10 V, I _D = -14 A		5.0	7.0		
		V _{GS} = -4.5 V, I _D = -10 A		8.0	12.0	mΩ	
		V_{GS} = -10 V, I _D = -14 A, T _J = 125 °C		6.2	10.4	1	
9 _{FS}	Forward Transconductance	$V_{DS} = -5 V, I_D = -14 A$		60		S	
Dynamic C _{iss}	Characteristics Input Capacitance			4130	5785	pF	
C _{oss}	Output Capacitance	V _{DS} = -15 V, V _{GS} = 0 V, f = 1 MHz		1355	1895	pF	
C _{rss}	Reverse Transfer Capacitance			1335	1870	pF	
Switching	Characteristics						
t _{d(on)}	Turn-On Delay Time			34	55	ns	
t _r	Rise Time	V _{DD} = -15 V, I _D = -14 A,		157	251	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		55	88	ns	
t _f	Fall Time			94	150	ns	
Q _q	Total Gate Charge	V _{GS} = 0 V to -10 V		96	135	nC	
Q _q	Total Gate Charge	$V_{GS} = 0 V \text{ to } -4.5 V V_{DD} = -15 V,$		58	81	nC	
Q _{gs}	Gate to Source Charge	I _D = -14 A		11		nC	
Q _{gd}	Gate to Drain "Miller" Charge			36		nC	
Drain-Sou	urce Diode Characteristics						
	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = -14 A (Note 2)		-0.8	-1.3	- V	
V _{SD}		$V_{GS} = 0 V, I_S = -2 A$ (Note 2)		-0.7	-1.2		
t _{rr}	Reverse Recovery Time			44	77	ns	
Q _{rr}	Reverse Recovery Charge	I _F = -14 A, di/dt = 100 A/μs		23	37	nC	

NOTES:

1. R_{61A} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0CA} is determined by the user's board design.



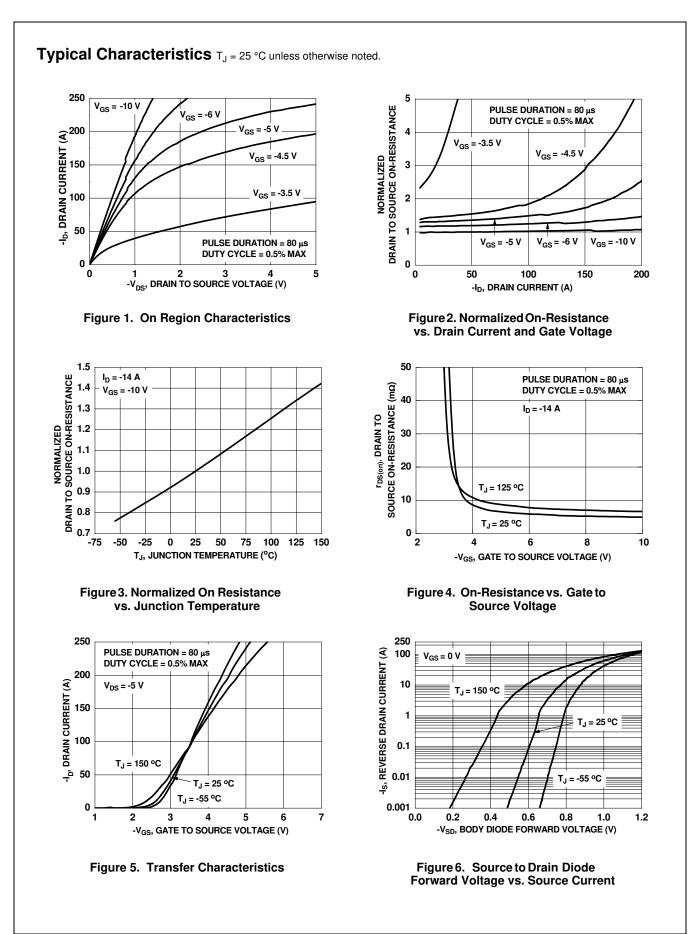
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

3. E_{AS} of 54 mJ is based on starting T_J = 25 °C, L = 3 mH, I_{AS} = 6 A, V_{DD} =30 V, V_{GS} = 10 V. 4. Pulsed ld please refer to Fig 11 SOA graph for more details.

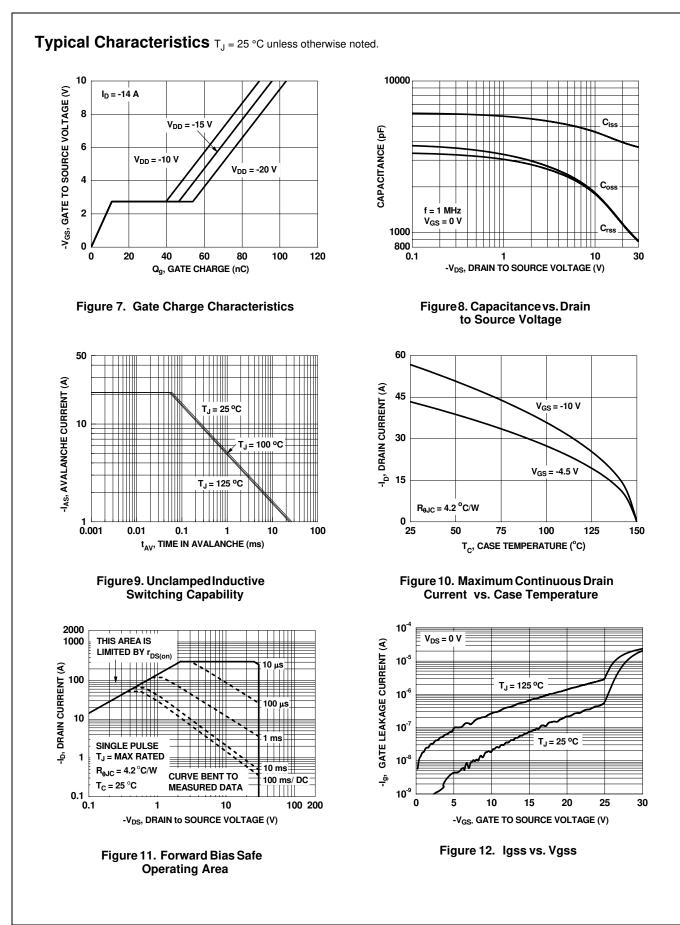
5. Computed continuous current limited to Max Junction Temperature only, actual continuous current will be limited by thermal & electro-mechanical application board design.

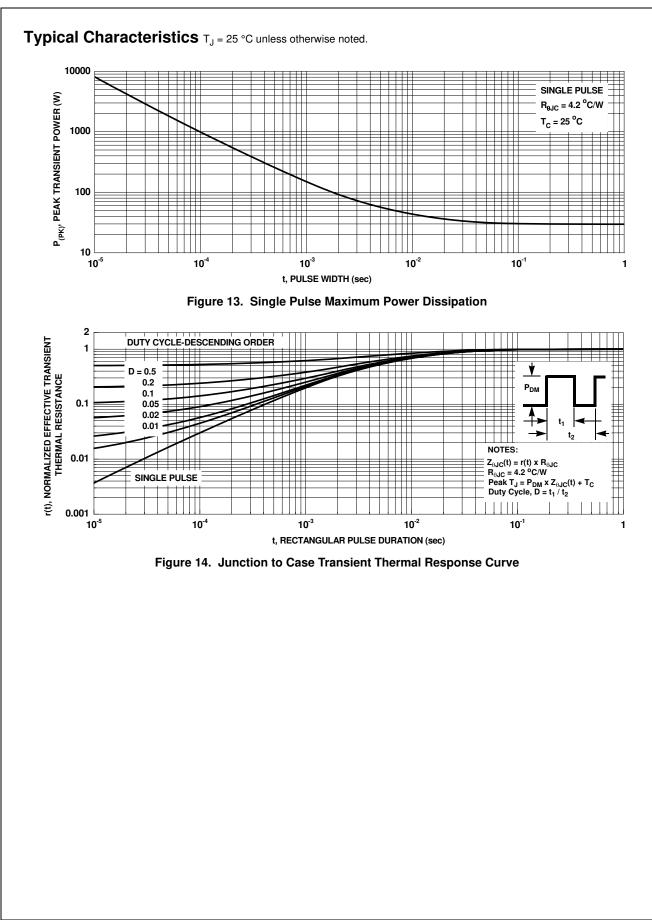
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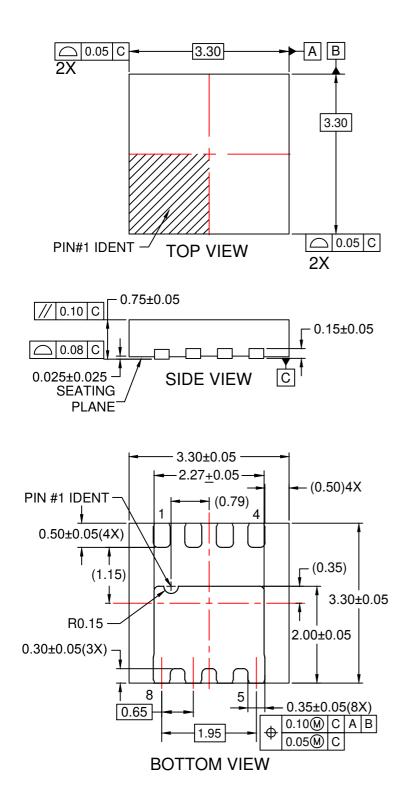
b) 125°C/W when mounted on a minimum pad

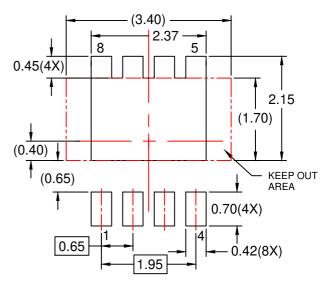












RECOMMENDED LAND PATTERN

NOTES:

- A. DOES NOT CONFORM TO JEDEC REGISTRATION MO-229
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-MLP08Srev3.



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